

LM185-1.2QML Micropower Voltage Reference Diode

Check for Samples: [LM185-1.2QML](#)

FEATURES

- Operating Current of $10\mu\text{A}$ to 20mA
- 1Ω Maximum Dynamic Impedance (Typical)
- Low Temperature Coefficient
- Radiation Qualified Option
 - 100 krad
 - Low Dose Rate Tested at 10 mrad/s

DESCRIPTION

The LM185-1.2 is a micropower 2-terminal band-gap voltage regulator diodes. Operating over a $10\mu\text{A}$ to 20mA current range, it features exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185-1.2 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-1.2 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-1.2 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life.

Further, the wide operating current allows it to replace older references with a tighter tolerance part.

Connection Diagrams

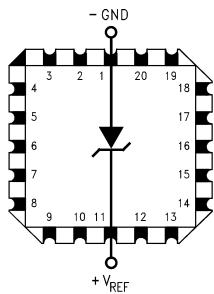


Figure 1. LCCC Package
See Package Number NAJ0020A

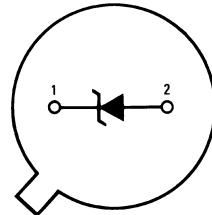


Figure 2. TO Package – Bottom View
See Package Number NDU0002A



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

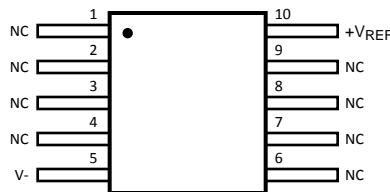
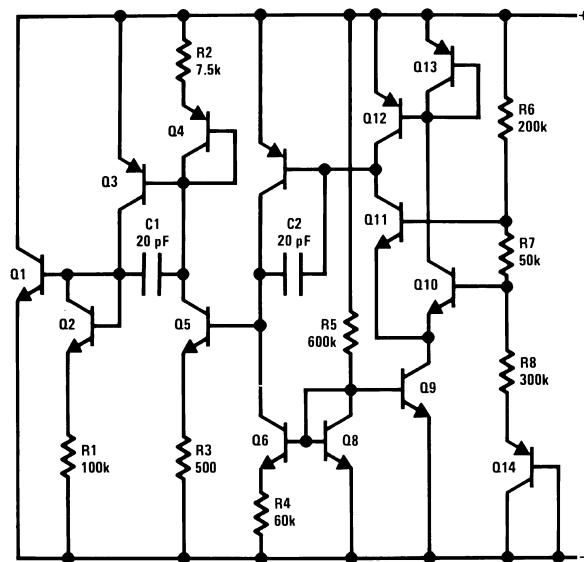


Figure 3. CLGA Package
See Package Number NAC0010A

Schematic Diagram



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾

Reverse Current			30mA
Forward Current			10mA
Operating Temperature Range			-55°C ≤ T _A ≤ +125°C
Maximum Junction Temperature (T _{Jmax}) ⁽²⁾			+150°C
Storage Temperature			-55°C ≤ T _A ≤ +150°C
Lead Temperature (Soldering 10 Seconds)	CLGA		260°C
	TO package		300°C
	20LD LCCC package		300°C
Thermal Resistance	θ _{JA}	TO (Still Air)	300°C/W
		TO (500LF / Min Air Flow)	139°C/W
		20LD LCCC (Still Air)	100°C/W
		20LD LCCC (500LF / Min Air Flow)	73°C/W
		CLGA (Still Air)	194°C/W
		CLGA (500LF / Min Air Flow)	128°C/W
	θ _{JC}	TO	57°C/W
		20LD LCCC	25°C/W
		CLGA	23°C/W
Package Weight (Typical)	TO		TBD
	20LD LCCC		TBD
	CLGA		210mg
ESD Tolerance ⁽³⁾			4KV

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional. For specifications and test conditions, see the Electrical Characteristics. The specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is P_{Dmax} = (T_{Jmax} - T_A)/θ_{JA} or the number given in the Absolute Maximum Ratings, whichever is lower.
- (3) Human body model, 1.5KΩ in series with 100pF.

Quality Conformance Inspection
Table 1. Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

LM185–1.2 Electrical Characteristics DC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
V_{Ref}	Reverse Breakdown Voltage	$I_R = 10\mu A$		1.223	1.247	V	1
		$I_R = 20\mu A$		1.205	1.26	V	2, 3
		$I_R = 1mA$		1.223	1.247	V	1
				1.205	1.26	V	2, 3
		$I_R = 20mA$		1.223	1.247	V	1
				1.205	1.26	V	2, 3
$\Delta V_{Ref} / \Delta I_R$	Reverse Breakdown Voltage Change with Current	$10\mu A \leq I_R \leq 1mA$		-1.0	1.0	mV	1
		$20\mu A \leq I_R \leq 1mA$		-1.5	1.5	mV	2, 3
		$1mA \leq I_R \leq 20mA$		-10.0	10.0	mV	1
				-20.0	20.0	mV	2, 3
V_F	Forward Bias Voltage	$I_F = 2mA$		-1.0	-0.4	V	1

LM185–1.2 Electrical Characteristics DC Drift Parameters

Delta calculations performed on QMLV devices at group B, subgroup 5, unless otherwise specified on the IPI.

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
V_R	Reverse Breakdown Voltage	$I_R = 10\mu A$		-0.01	0.01	V	1
		$I_R = 20mA$		-0.01	0.01	V	1

LM185BY–1.2 Electrical Characteristics DC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
V_{Ref}	Reverse Breakdown Voltage	$I_R = 10\mu A$		1.223	1.247	V	1
		$I_R = 20\mu A$		1.205	1.26	V	2, 3
		$I_R = 1mA$		1.223	1.247	V	1
				1.205	1.26	V	2, 3
		$I_R = 20mA$		1.223	1.247	V	1
				1.205	1.26	V	2, 3
$\Delta V_{Ref} / \Delta I_R$	Reverse Breakdown Voltage Change with Current	$10\mu A \leq I_R \leq 1mA$		-1.0	1.0	mV	1
		$20\mu A \leq I_R \leq 1mA$		-1.5	1.5	mV	2, 3
		$1mA \leq I_R \leq 20mA$		-10.0	10.0	mV	1
				-20.0	20.0	mV	2, 3
V_F	Forward Bias Voltage	$I_F = 2mA$		-1.0	-0.4	V	1
T_C	Temperature Coefficient		(1)		50	PPM/°C	2, 3

(1) The average temperature coefficient is defined as the maximum deviation of reference voltage, at all measured temperatures between the operating T_{Min} & T_{Max} , divided by $(T_{Max} - T_{Min})$. The measured temperatures ($T_{Measured}$) are $-55^{\circ}C$, $25^{\circ}C$, & $125^{\circ}C$ or $\Delta V_{Ref} / (T_{Max} - T_{Min})$

LM185-1.2RLQV SMD 5962R8759461 Post 100 krad Electrical Characteristics DC Parameters⁽¹⁾⁽²⁾

Symbol	Parameter	Conditions	Notes	Min	Max	Units	Sub-groups
ΔV_{Ref}	Change in Reverse Breakdown Voltage	$I_R = 10\mu\text{A}$	(3)	-3	3	%	1
		$I_R = 1\text{mA}$	(3)	-3	3	%	1
		$I_R = 20\text{mA}$	(3)	-2.5	2.5	%	1
$\Delta V_{\text{Ref}} / \Delta I_R$	Reverse Breakdown Voltage Change with Current	$10\mu\text{A} \leq I_R \leq 1\text{mA}$		-15	15	mV	1
		$1\text{mA} \leq I_R \leq 20\text{mA}$		-25	25	mV	1
V_F	Forward Bias Voltage	$I_F = 2\text{mA}$		-1.0	-0.4	V	1

- (1) Radiation hardness assured (RHA) products are those with an "RLQV" suffix in the Texas Instruments' part number or those with an "R" in the SMD number, following "5962".
- (2) Testing and qualification for RHA products is done on a wafer level according to MIL-STD-883, Test Method 1019. Testing is performed with a 1.5X overtest. To be rated at 100 krad(Si) units are tested to 150 krad(Si) with all parameters remaining inside the post 100 krad Electrical DC test limits in this table. Interim test points are taken at 50, 75 and 100 krad(Si).
- (3) Change from the 0 rad reading.

Typical Performance Characteristics

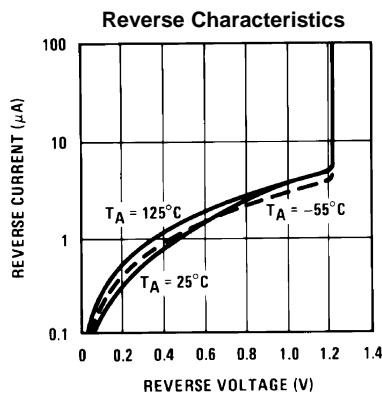


Figure 4.

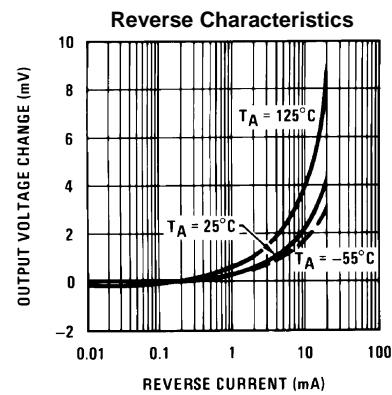


Figure 5.

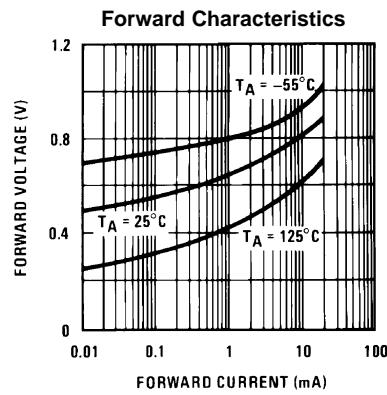


Figure 6.

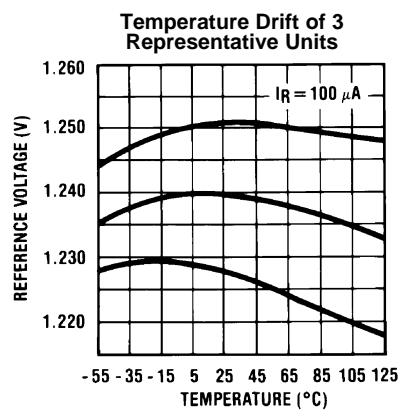


Figure 7.

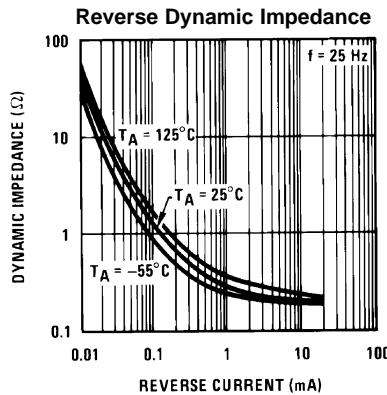


Figure 8.

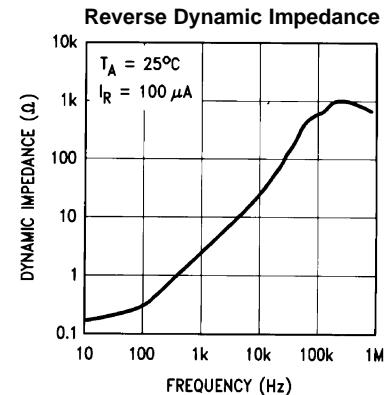
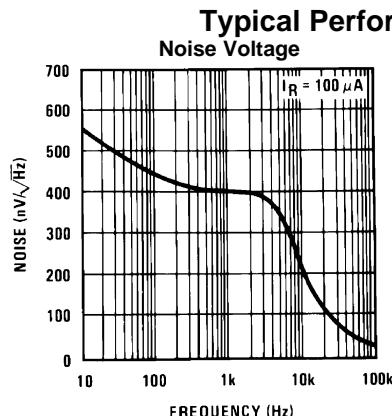
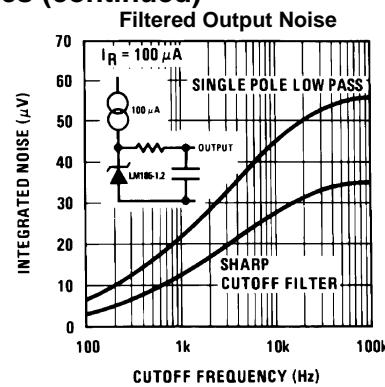
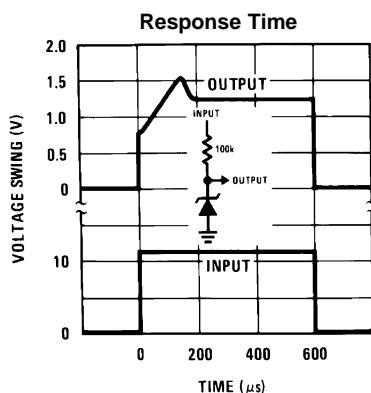
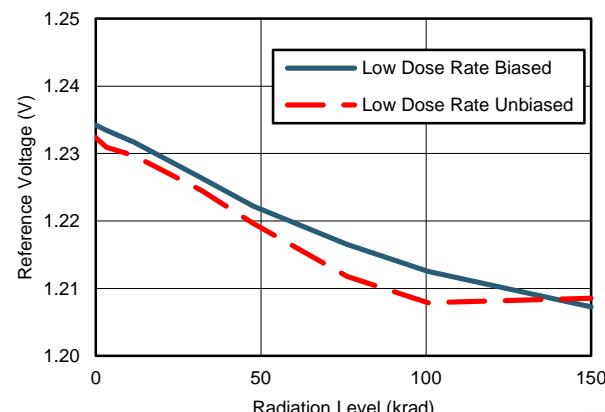
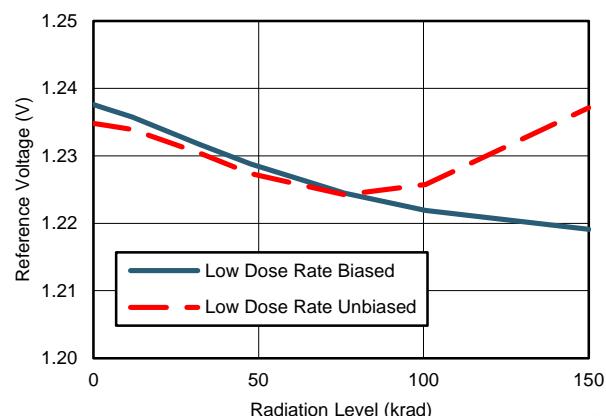


Figure 9.


Figure 10.

Figure 11.

Figure 12.

Figure 13. V_{Ref} Radiation Drift at $I_R = 10 \mu A$

Figure 14. V_{Ref} Radiation Drift at $I_R = 20 \text{ mA}$

Typical Applications

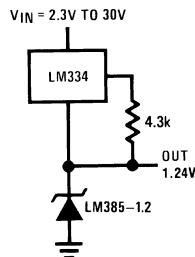


Figure 15. Wide Input Range Reference

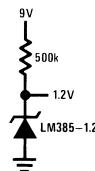


Figure 16. Micropower Reference from 9V Battery

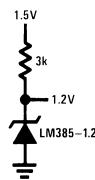
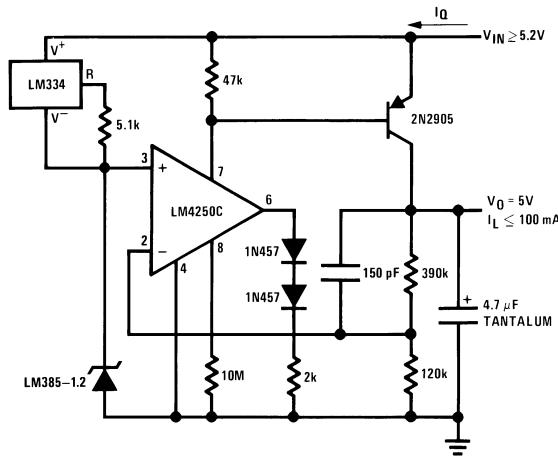
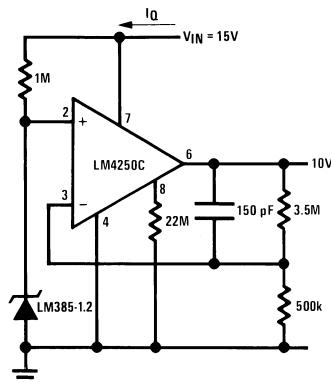


Figure 17. Reference from 1.5V Battery



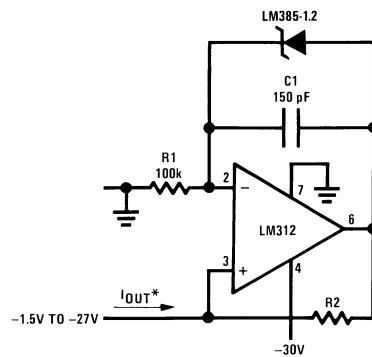
* $I_Q \approx 30\mu A$

Figure 18. Micropower* 5V Regulator



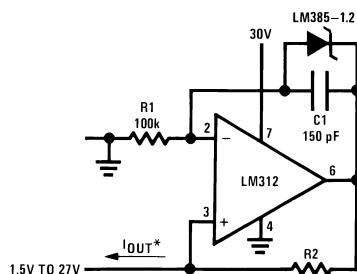
$*I_Q \approx 20\mu A$ standby current

Figure 19. Micropower* 10V Reference

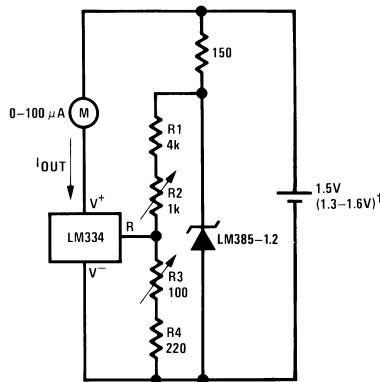


$$*I_{OUT} = \frac{1.23V}{R_2}$$

Figure 20. Precision 1µA to 1mA Current Sources



METER THERMOMETERS



Calibration

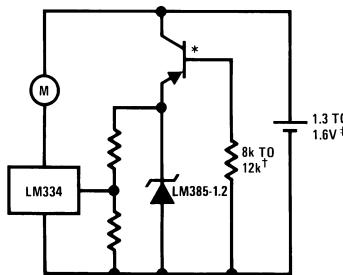
1. Short LM385-1.2, adjust R3 for $I_{OUT} = \text{temp at } 1\mu\text{A}/\text{K}$

2. Remove short, adjust R2 for correct reading in centigrade

$\dagger I_Q \text{ at } 1.3\text{V} = 500\mu\text{A}$

$I_Q \text{ at } 1.6\text{V} = 2.4\text{mA}$

Figure 21. 0°C-100°C Thermometer

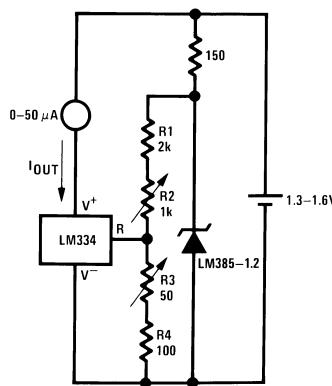


*2N3638 or 2N2907 select for inverse $H_{FE} \approx 5$

†Select for operation at 1.3V

‡ $I_Q \approx 600\mu\text{A}$ to $900\mu\text{A}$

Figure 22. Lower Power Thermometer

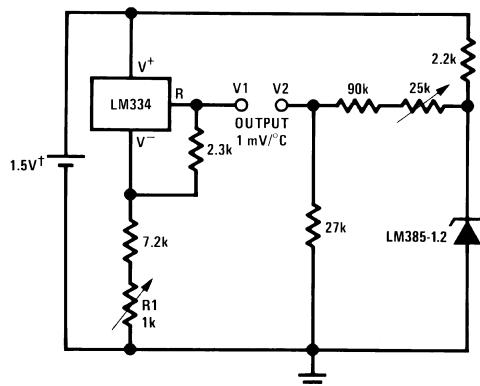


Calibration

1. Short LM385-1.2, adjust R3 for $I_{OUT} = \text{temp at } 1.8\mu\text{A}/\text{K}$

2. Remove short, adjust R2 for correct reading in °F

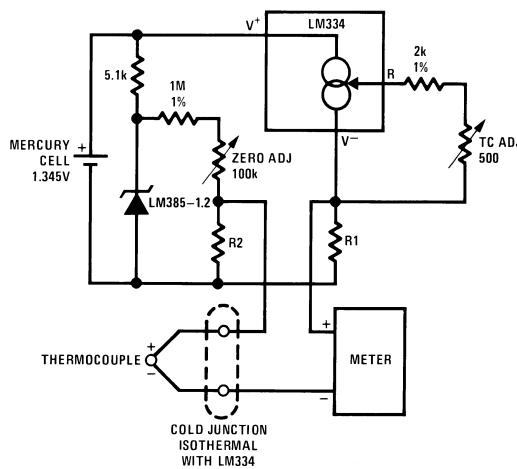
Figure 23. 0°F-50°F Thermometer



Calibration

1. Adjust R1 so that $V1 = \text{temp at } 1\text{mV/}^{\circ}\text{K}$
2. Adjust $V2$ to 273.2mV
 $\dagger I_Q$ for 1.3V to 1.6V battery voltage = $50\mu\text{A}$ to $150\mu\text{A}$
 Typical supply current $50\mu\text{A}$

Figure 24. Centigrade Thermometer



Adjustment Procedure

1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.
2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

Figure 25. Micropower Thermocouple Cold Junction Compensator

Thermocouple Type	Seebeck Coefficient ($\mu\text{V}^\circ\text{C}$)	R1 (Ω)	R2 (Ω)	Voltage Across R1 @ 25°C (mV)	Voltage Across R2 (mV)
J	52.3	523	1.24k	15.60	14.32
T	42.8	432	1k	12.77	11.78
K	40.8	412	953	12.17	11.17
S	6.4	63.4	150	1.908	1.766

REVISION HISTORY SECTION

Released	Revision	Section	Originator	Changes
10/07/05	A	New Release, Corporate format	L. Lytle	2 MDS data sheets converted into one Corp. data sheet format. MNLM185-1.2-X Rev 2A3 and MNLM185BY-1.2-X Rev 0B0 data sheets will be archived.
03/27/13	A	All		Changed layout of National Data Sheet to TI format
01/07/14	B	Features, Electrical Characteristics, Typical Performance Characteristics	K. Kruckmeyer	Added post irradiation test limits and typical radiation drift plots for radiation qualified option.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8759401XA	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	8759401XA Q	Samples
5962-8759401YA	ACTIVE	CFP	NAC	10	54	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	LM185WG-1.2/883 Q 5962-8759401YA ACO 01YA >T	Samples
5962-8759405XA	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	8759405XA Q	Samples
5962R8759461VXA	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	R8759461VXA Q	Samples
LM185BYH1.2-SMD	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	8759405XA Q	Samples
LM185H-1.2-SMD	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	8759401XA Q	Samples
LM185H-1.2/883	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	LM185-1.2 Q	Samples
LM185H-1.2RLQV	ACTIVE	TO	NDU	2	20	Non-RoHS & Non-Green	Call TI	Call TI	-55 to 125	R8759461VXA Q	Samples
LM185WG-1.2/883	ACTIVE	CFP	NAC	10	54	Non-RoHS & Green	Call TI	Level-1-NA-UNLIM	-55 to 125	LM185WG-1.2/883 Q 5962-8759401YA ACO 01YA >T	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

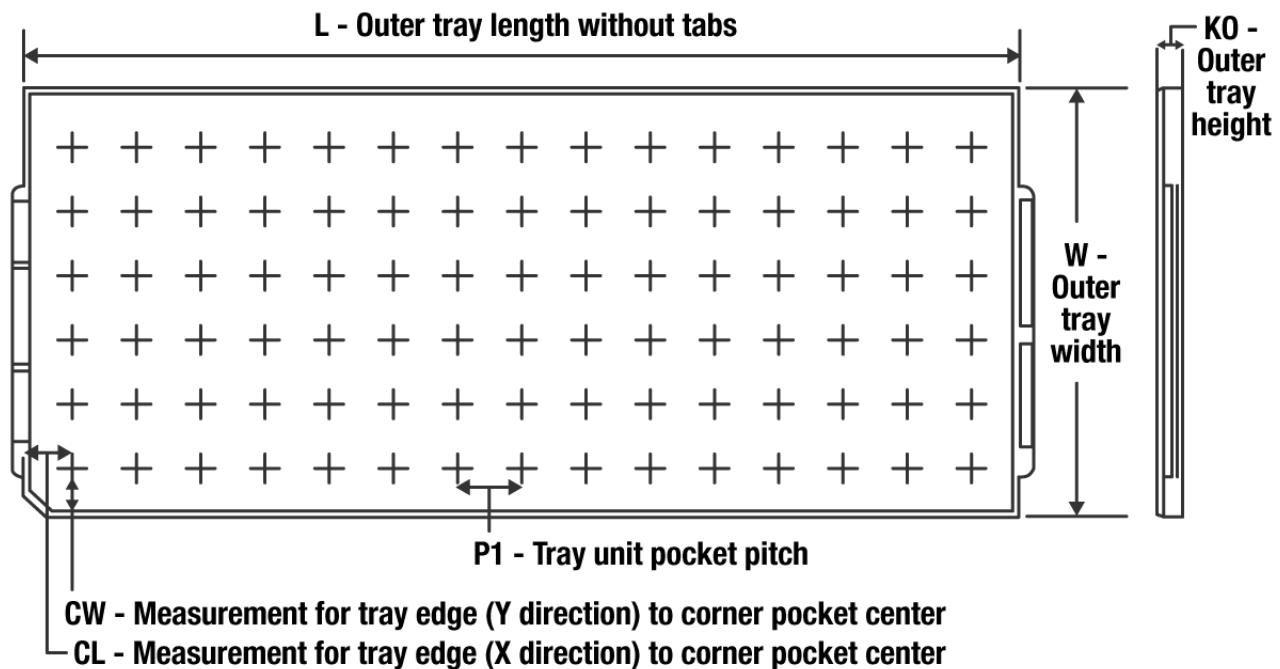
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF LM185-1.2QML, LM185-1.2QML-SP :

- Military : [LM185-1.2QML](#)
- Space : [LM185-1.2QML-SP](#)

NOTE: Qualified Version Definitions:

- Military - QML certified for Military and Defense Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

TRAY


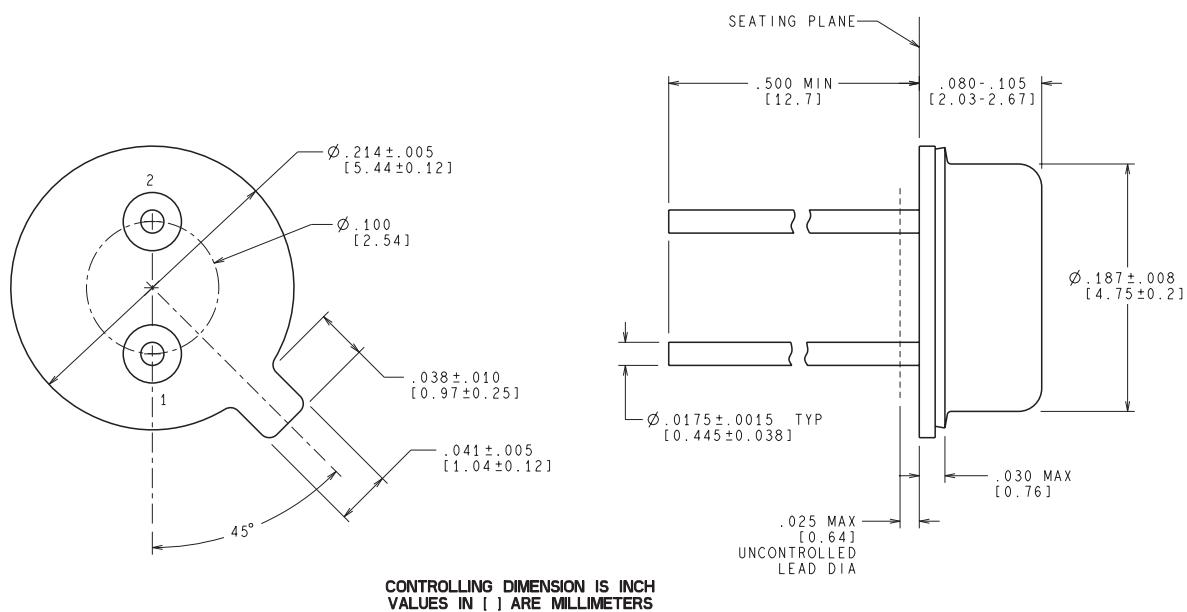
Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	K0 (µm)	P1 (mm)	CL (mm)	CW (mm)
5962-8759401XA	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
5962-8759401YA	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08
5962-8759405XA	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
5962R8759461VXA	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
LM185BYH1.2-SMD	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
LM185H-1.2-SMD	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
LM185H-1.2/883	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
LM185H-1.2RLQV	NDU	TO-CAN	2	20	2 X 10	150	126.49	61.98	10922	11.43	11.81	19.2
LM185WG-1.2/883	NAC	CFP	10	54	6 X 9	100	101.6	101.6	8001	2.78	16.08	16.08

MECHANICAL DATA

NDU0002A



H02A (Rev F)

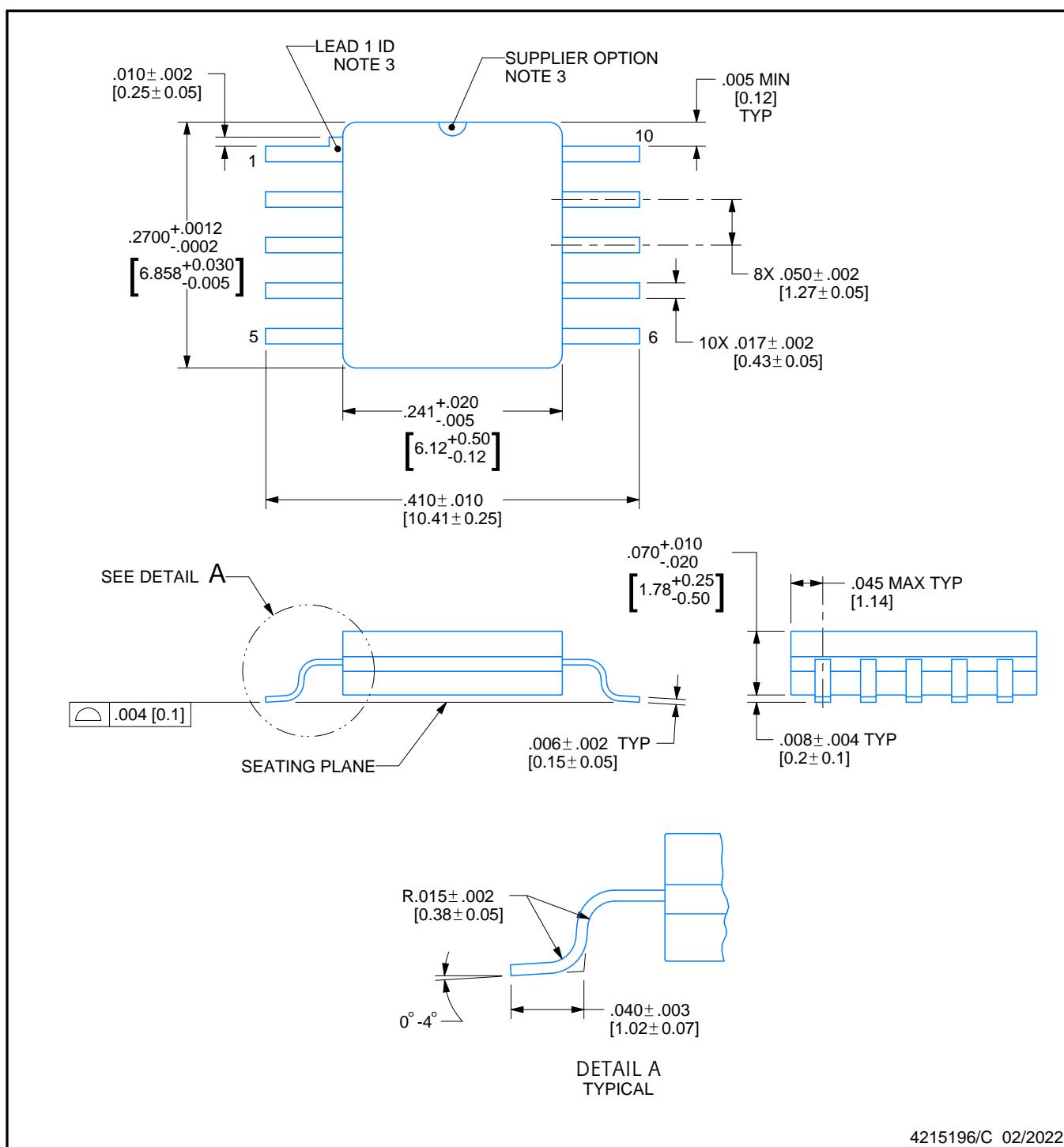


PACKAGE OUTLINE

NAC0010A

CFP - 2.33mm max height

CERAMIC FLATPACK



NOTES:

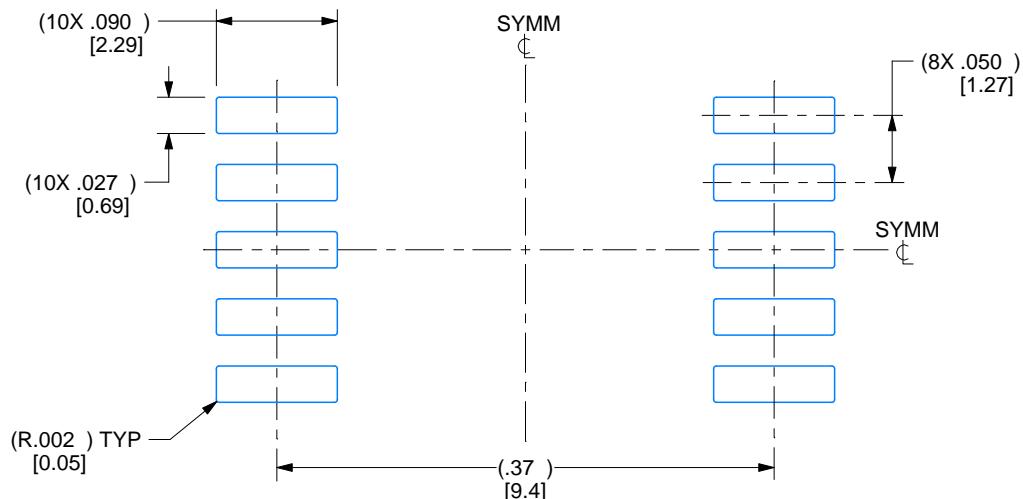
- All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- For solder thickness and composition, see the "Lead Finish Composition/Thickness" link in the packaging section of the Texas Instruments website
- Lead 1 identification shall be:
 - A notch or other mark within this area
 - A tab on lead 1, either side
- No JEDEC registration as of December 2021

EXAMPLE BOARD LAYOUT

NAC0010A

CFP - 2.33mm max height

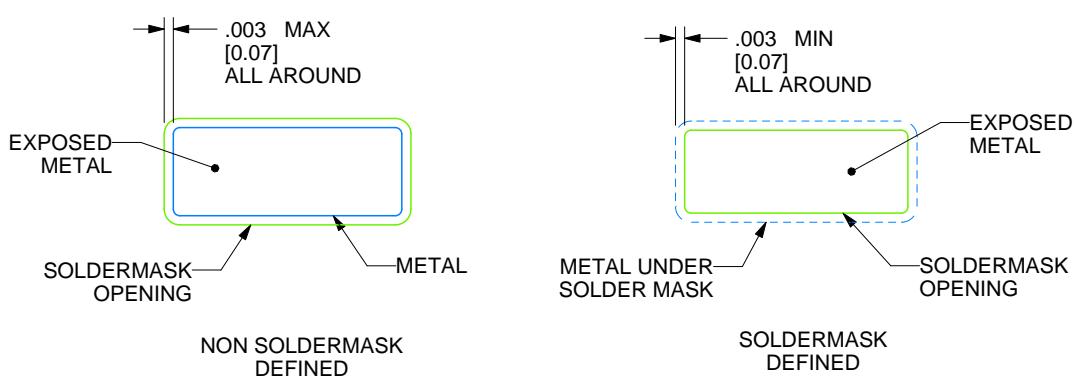
CERAMIC FLATPACK



LAND PATTERN EXAMPLE

EXPOSED METAL SHOWN

SCALE: 7X



4215196/C 02/2022

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2022, Texas Instruments Incorporated